MOSFET – Dual, P-Channel with ESD Protection, Small Signal, SOT-563

-20 V, -430 mA

Features

- Low R_{DS(on)} Improving System Efficiency
- Low Threshold Voltage
- ESD Protected Gate
- Small Footprint 1.6 x 1.6 mm
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Management
- Cell Phones, Digital Cameras, PDAs, Pagers, etc.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted.)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	-20	V
Gate-to-Source Voltage			V _{GS}	±6.0	V
Continuous Drain Current	Steady	$T_A = 25^{\circ}C$	1-	-430	mA
(Note 1)	State	$T_A = 85^{\circ}C$	Ι _D	-310	
Power Dissipation (Note 1)	Stead	dy State	P _D	250	mW
Continuous Drain Current (Note 1)	t≤5s	$T_A = 25^{\circ}C$	I _D	-455	mA
	1 - 00	$T_A = 85^{\circ}C$	טי	-328	
Power Dissipation (Note 1)	t ≤ 5 s		P _D	280	mW
Pulsed Drain Current	t _p = 10 μs		I _{DM}	-750	mA
Operating Junction and Storage Temperature			T _J , T _{STG}	–55 to 150	°C
Source Current (Body Diode)			IS	-350	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		ΤL	260	°C	

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	Bau	500	°C/W
Junction–to–Ambient – t \leq 5 s (Note 1)	$R_{\theta JA}$	447	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

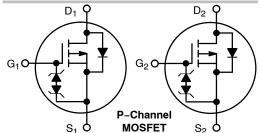
1. Surface mounted on FR4 board using 1 in. sq. pad size

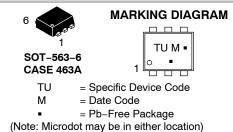
(Cu. area = 1.127 in. sq. [1 oz.] including traces).

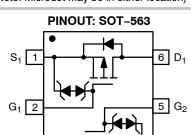
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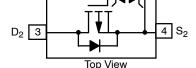
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V _{(BR)DSS}	R _{DS(on)} Typ	I _D Max
	0.5 Ω @ –4.5 V	
–20 V	0.6 Ω @ –2.5 V	–430 mA
	1.0 Ω @ –1.8 V	









ORDERING INFORMATION

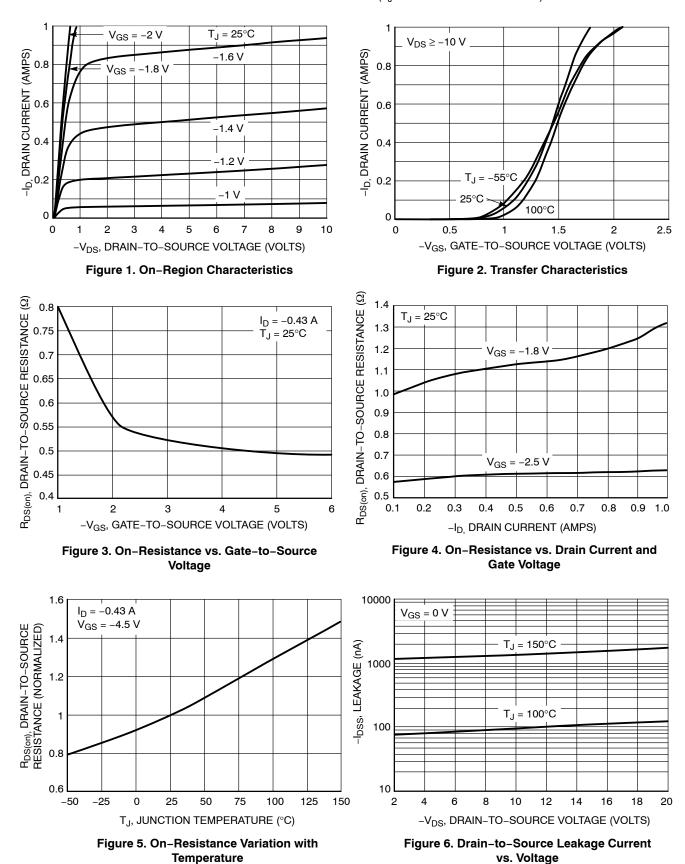
Device	Package	Shipping [†]
NTZD3152PT1G	SOT-563	4000 / Tana & Daal
NTZD3152PT1H	(Pb-Free)	4000 / Tape & Reel
NTZD3152PT5H	SOT-563 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted.)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS		-		-	-	-	-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I _D = -250 μA		-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				18		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = -16 V	T _J = 25°C T _J = 125°C			-1.0 -2.0	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±4.5 V				±2.0	μΑ
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D$	= –250 μA	-0.45		-1.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-1.9		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V_{GS} = -4.5 V, I _D = -430 mA			0.5	0.9	Ω
		V_{GS} = -2.5 V, I _D = -300 mA		0.6	1.2	1	
		$V_{GS} = -1.8 \text{ V}, \text{ I}_{D} = -150 \text{ mA}$			1.0	2.0	1
Forward Transconductance	9 FS	V _{DS} = -10 V, I _D	= -430 mA		1.0		S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}	V_{GS} = 0 V, f = 1.0 MHz, V_{DS} = –16 V			105	175	pF
Output Capacitance	C _{OSS}				15	30	
Reverse Transfer Capacitance	C _{RSS}				10	20	1
Total Gate Charge	Q _{G(TOT)}				1.7	2.5	nC
Threshold Gate Charge	Q _{G(TH)}	V_{GS} = -4.5 V, V_{DS} = -10 V, I _D = -215 mA			0.1		7
Gate-to-Source Charge	Q _{GS}				0.3		
Gate-to-Drain Charge	Q _{GD}				0.4		
SWITCHING CHARACTERISTICS (Not	e 3)						
Turn-On Delay Time	t _{d(on)}				10		ns
Rise Time	t _r	V_{GS} = –4.5 V, V_{DD} = –10 V, I_{D} = –215 mA, R_{G} = 10 Ω			12		
Turn-Off Delay Time	t _{d(off)}				35		
Fall Time	t _f				19		
DRAIN-SOURCE DIODE CHARACTER	RISTICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = –350 mA	T _J = 25°C		-0.8	-1.2	V
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V}, \text{ dI}_{SD}/\text{d}$ $I_S = -350$			13		ns

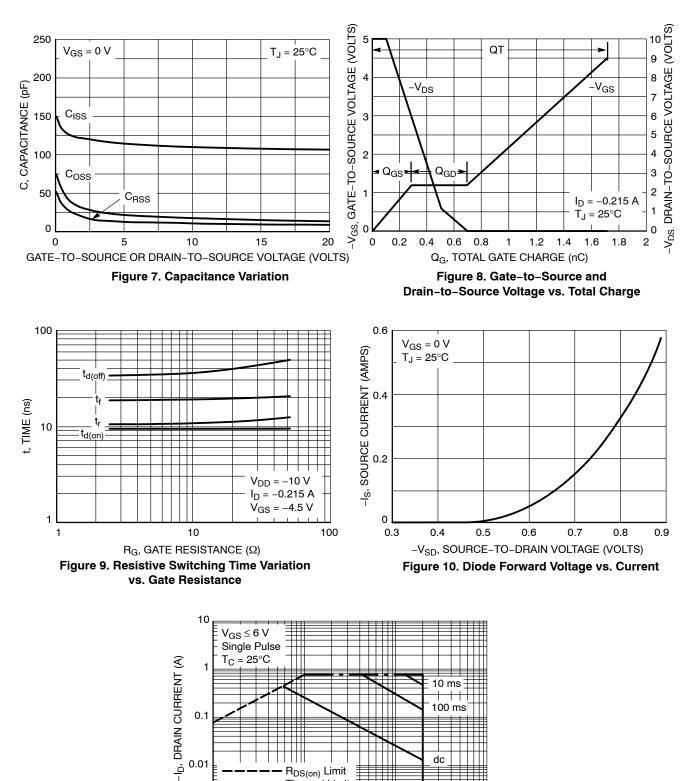
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Pulse Test: pulse width ≤ 300 µs, duty cycle ≤ 2%.
Switching characteristics are independent of operating junction temperatures.



TYPICAL PERFORMANCE CURVES (T_J = 25° C unless otherwise noted)







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-V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V) Figure 11. Safe Operating Area

R_{DS(on)} Limit Thermal Limit Package Limit

1111

1

0.01

0.001

0.1

dc

100

10

6Х





SOT-563, 6 LEAD CASE 463A ISSUE H

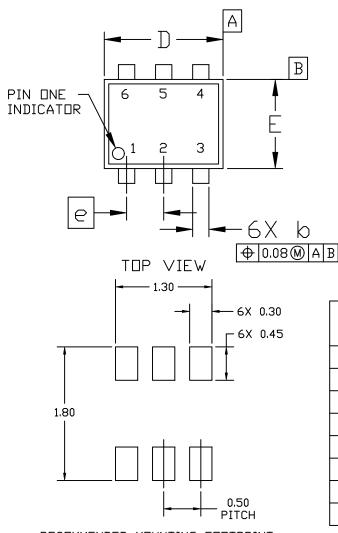
DATE 26 JAN 2021

ALE 4:1

NDTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.

А

- 1. DIMENSIONING AND TOLERANCING PER A 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF BASE MATERIAL.



SIDE VIEW MILLIMETERS DIM MIN. NDM. MAX. 0.50 0.55 0.60 Α 0.17 0.22 0.27 b 0.08 0.13 0.18 С 1.50 1.60 1.70 D Ε 1.10 1.20 1.30 0.50 BSC e L 0.10 0.20 0.30 H_E 1.50 1.60 1.70

(

RECOMMENDED MOUNTING FOOTPRINT* * For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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PIN 1. EMITTER 1	PIN 1. EMITTER 1	PIN 1. CATHIDE 1
2. BASE 1	2. EMITTER 2	2. CATHIDE 1
3. COLLECTOR 2	3. BASE 2	3. ANUDE/ANUDE 2
4. EMITTER 2	4. COLLECTOR 2	4. CATHIDE 2
5. BASE 2	5. BASE 1	5. CATHIDE 2
6. COLLECTOR 1	6. COLLECTOR 1	6. ANUDE/ANUDE 1
STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. COLLECTOR	PIN 1. CATHEDE	PIN 1. CATHODE
2. COLLECTOR	2. CATHEDE	2. ANODE
3. BASE	3. ANEDE	3. CATHODE
4. EMITTER	4. ANEDE	4. CATHODE
5. COLLECTOR	5. CATHEDE	5. CATHODE
6. COLLECTOR	6. CATHEDE	6. CATHODE
STYLE 7:	STYLE 8:	STYLE 9:
PIN 1. CATHODE	PIN 1. DRAIN	PIN 1. SDURCE 1
2. ANODE	2. DRAIN	2. GATE 1
3. CATHODE	3. GATE	3. DRAIN 2
4. CATHODE	4. SDURCE	4. SDURCE 2
5. ANODE	5. DRAIN	5. GATE 2
6. CATHODE	6. DRAIN	6. DRAIN 1
STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2 4. ANODE 2 5. N/C 6. ANODE 1	STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	

6. COLLECTOR 2

DATE 26 JAN 2021

GENERIC **MARKING DIAGRAM***



XX = Specific Device Code

M = Month Code

. = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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